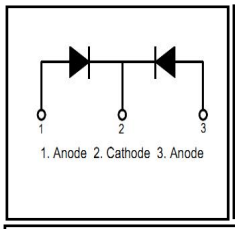
30A 200V SchottkyBarrierDiode

1 Description

Dual center tab Schottky rectifier suited for High Frequency server and telecom base station SMPS. Packaged in TO, this device combines high current rating and low volume to enhance both reliability and power density of the application.

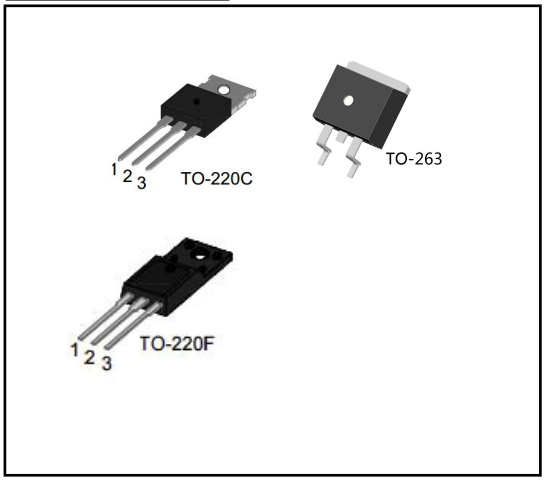
TO-220F provides insulation voltage rated at 2000V RMS from all three terminals to external heatsink. TO-220F series comply with UL standards (File ref:E252906).



V_{BR} = 200V

$V_{F(single)(Max)}$= 0.88V

$I_{F(AV)(single)}$ = 15A



2 Features

- High junction temperature capabiliy
- Low leakage current
- Low thermal resistance
- High frequency operation
- Avalanche specification

3 Applications

- Switching Power Supply
- Power Switching Circuits
- General Purpose

4 Electrical Characteristics

4.1 Absolute Maximum Ratings （Tc=25℃,unless otherwise noted）

PARAMETER		SYMBOL	VALUE	UNIT
Peak Repetitive Reverse Voltage		V_{RRM}	200	V
RMS Reverse Voltage		$V_{R(RMS)}$	160	V
DC Blocking Voltage		V_R	200	V
Average Rectified Forward Current(single)	TO-3P/220/263/3PN,T_C=120℃	$I_{F(AV)}$	15	A
Average Rectified Forward Current(double)	TO-220F,T_C=100℃		30	A
Repetitive Peak Surge Current(single)		I_{FRM}	20	A
Nonrepetitive Peak Surge Current(single)	t=8.3ms	I_{FSM}	250	A
Avalanche Energy(single)	L=1mH	E_{AS}	50	mJ
Operating Junction Temperature Range		T_j	-55～175	℃
Storage Temperature Range		T_{stg}	-55～175	℃

4.2 Thermal Characteristics

PARAMETER	SYMBOL	VALUE		UNIT
		TO-220/263	TO-220F	
Thermal Resistance, Junction to Case-sink	R_{thJC}	0.95	1.5	℃/W

4.3 Electrical Characteristics (Tc=25℃,unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Maximum Instantaneous Forward Voltage	V_F	I_F = 5A	-	0.73	-	V
		I_F = 10A	-	0.79	-	V
		I_F = 15A	-	0.82	0.88	V
		I_F = 15A, T_C = 125℃	-	0.74	-	V
		I_F = 20A	-	0.87	-	V
		I_F = 30A	-	0.90	-	V
Maximum Instantaneous Reverse	I_R	V_R = 200V	-	1.0	50	uA
		V_R = 200V, T_C = 125℃	-	-	10	mA
Total capacitance	C_{tot}	V_R=10V f=1MHz	-	180	-	pF
DC Blocking Voltage	V_{BR}	I_R=100uA	200	240	-	V

DEFINITIONS

VF = Instantaneous forward voltage (pw = 300μs, D = 2%).

IR = Instantaneous reverse current.

RθJC = Thermal resistance junction to case.

pw = pulse width.

D = duty cycle.

5 Typical characteristics diagrams

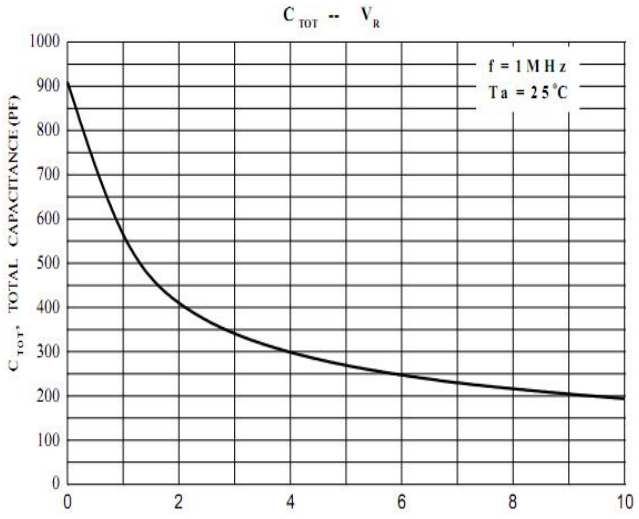


FIGURE 1. Total capacitance vs Voltage

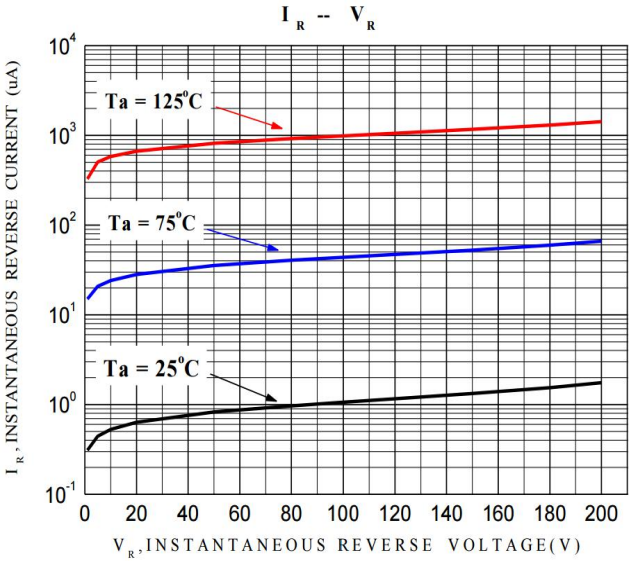


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

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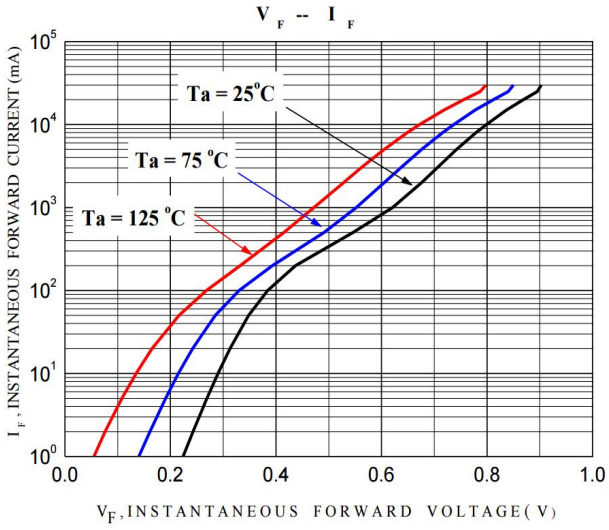


FIGURE 3. FORWARD CURRENT vs FORWARD VOLTAGE

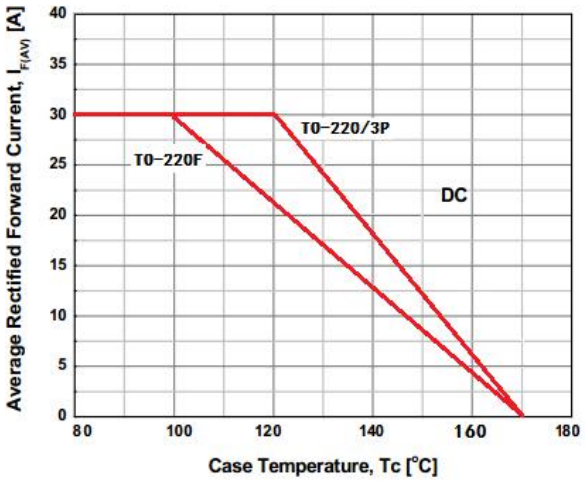


FIGURE 4. CURRENT DERATING CURVE

6 Typical Test Circuit and Waveform

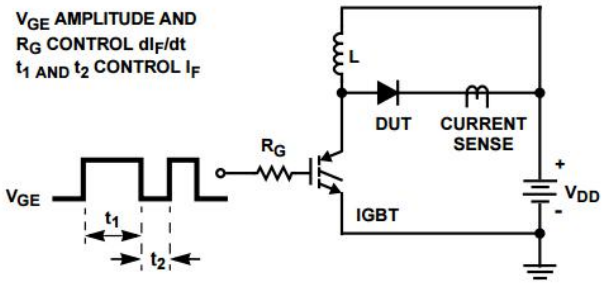


FIGURE 5. trr TEST CIRCUIT

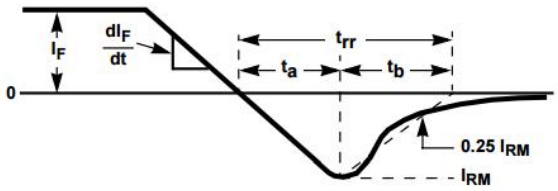


FIGURE 6. trr WAVEFORMS AND DEFINITIONS

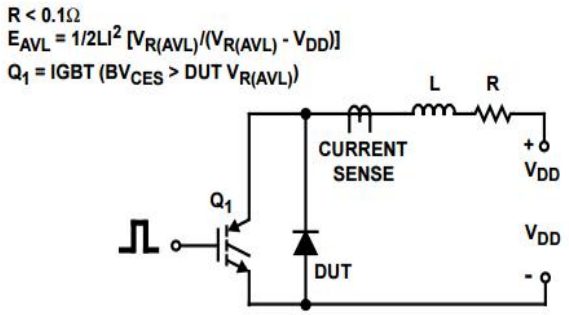


FIGURE 7. AVALANCHE ENERGY TEST CIRCUIT FIGURE

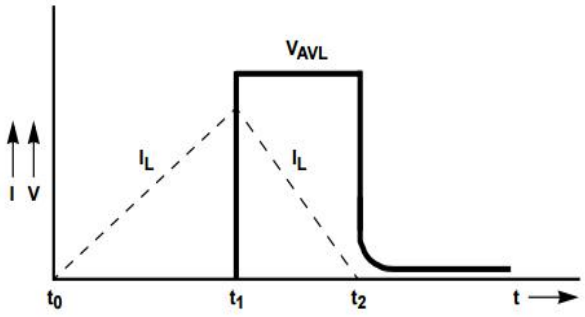
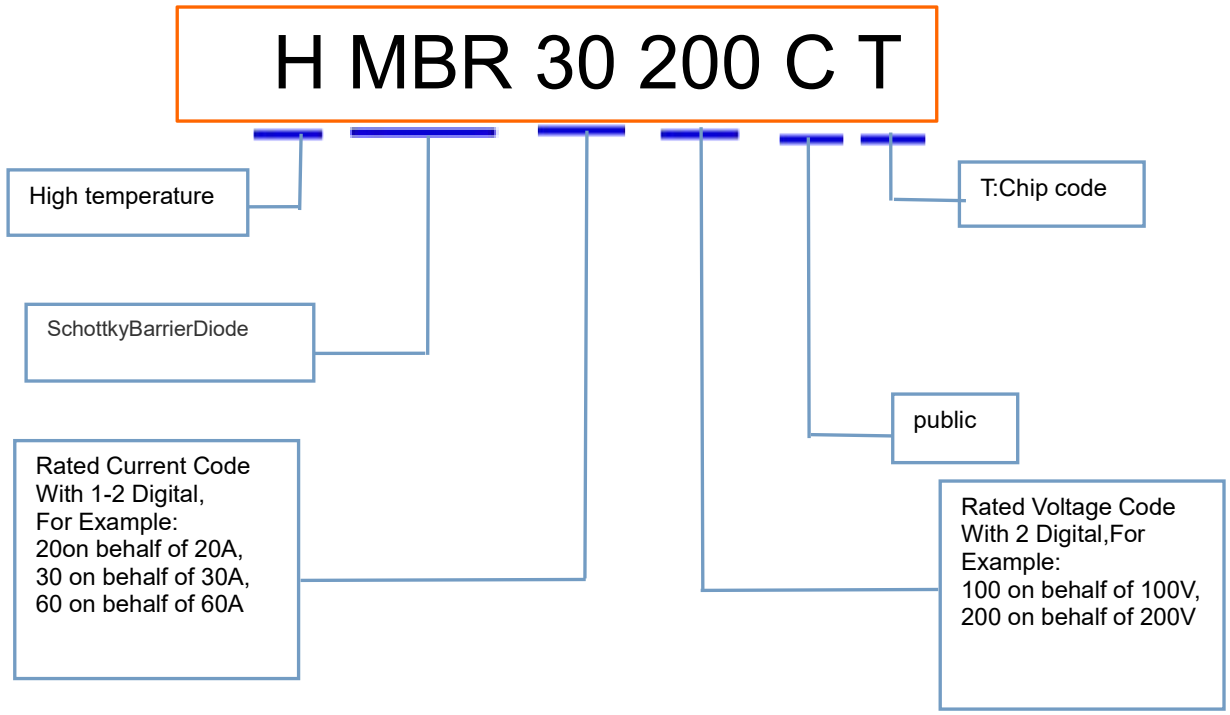


FIGURE8. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

7 Product Names Rules

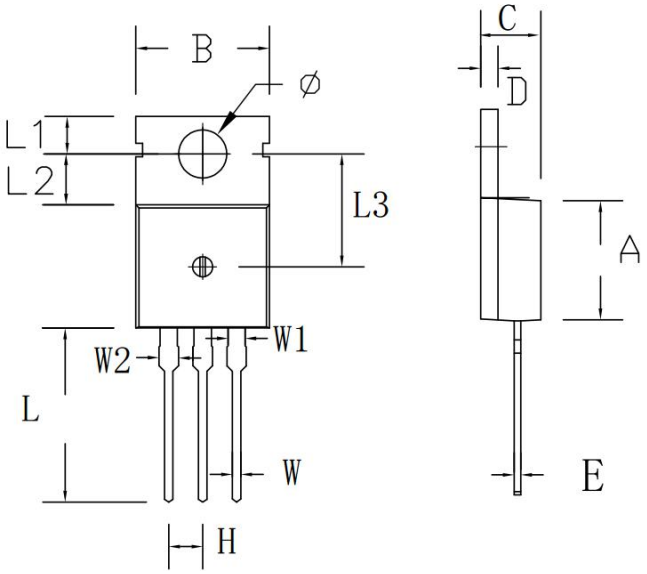


8 Product Specifications and Packaging Models

Product Model	Package Type	Mark Name	RoHS	Package	Quantity
HMBR30200CT	TO-220	HMBR30200CT	Pb-free	Tube	1000/box
HMBRF30200CT	TO-220F	HMBR30200CT	Pb-free	Tube	1000/box
HMBR30200CT	TO-263	HMBR30200CT	Pb-free	Tube	1000/box

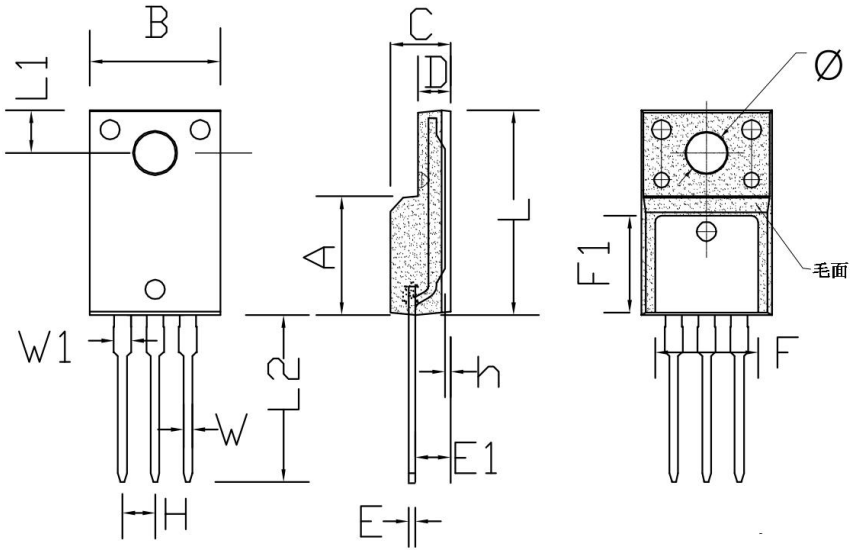
9 Dimensions

TO-220 PACKAGE OUTLINE DIMENSIONS



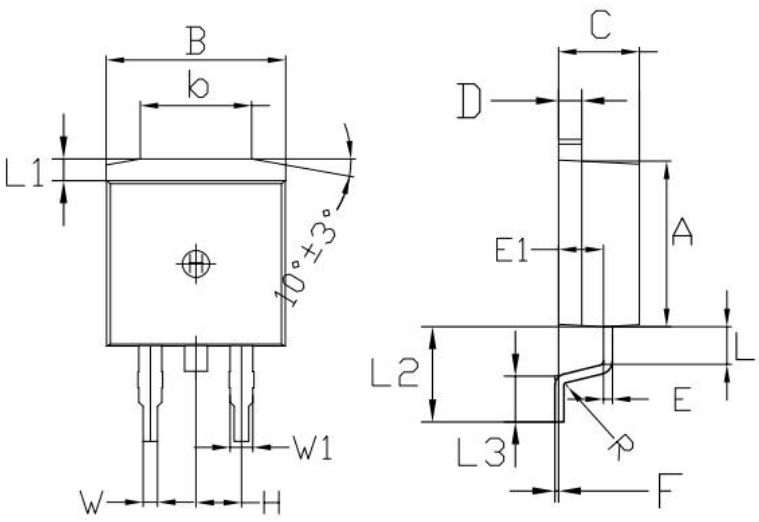
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	min.	max.	min.	max.
A	8.80	9.30	0.346	0.366
B	9.70	10.30	0.382	0.406
C	4.25	4.75	0.167	0.187
D	1.20	1.45	0.047	0.057
E	0.40	0.60	0.016	0.024
H	2.54 TYP		0.100 TYP	
W	0.60	0.95	0.024	0.037
W1	1.05	1.45	0.041	0.057
W2	1.20	1.60	0.047	0.063
L	12.60	13.40	0.496	0.528
L1	2.45	2.95	0.096	0.116
L2	3.45	3.95	0.136	0.156
L3	8.15	8.65	0.321	0.341
Φ	3.50	3.90	0.138	0.154

TO-220F PACKAGE OUTLINE DIMENSIONS



Symbol	DimensionsIn Millimeters		DimensionsIn Inches	
	min.	max.	min.	max.
A	8.80	9.30	0.346	0.366
B	10.00	10.50	0.394	0.413
C	4.30	4.90	0.169	0.193
D	2.30	2.70	0.091	0.106
L	15.55	16.15	0.612	0.636
h	0.40	0.60	0.016	0.024
L1	3.15	3.55	0.124	0.140
L2	12.65	13.35	0.498	0.526
W	0.70	0.90	0.028	0.035
W1	1.15	1.55	0.045	0.061
H	2.54 TYP		0.100 TYP	
E	0.48	0.53	0.019	0.021
Φ	2.90	3.40	0.114	0.134
E1	2.40	2.90	0.094	0.114
F	7.75	8.25	0.305	0.325
F1	7.35	7.85	0.289	0.309

TO-263 PACKAGE OUTLINE DIMENSIONS



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	min.	max.	min.	max.
A	8.80	9.30	0.346	0.366
B	9.70	10.30	0.382	0.406
C	4.25	4.75	0.167	0.187
D	1.20	1.45	0.047	0.057
E	0.40	0.60	0.016	0.024
L	12.25	13.75	0.482	0.541
L1	1.15	1.45	0.045	0.057
R	0.24	0.26	0.0095	0.0102
W	0.80	0.82	0.0315	0.0323
W1	1.20	1.30	0.047	0.051
H	2.54 TYP		0.200 TYP	
b	5.50	6.50	0.216	0.256
E1	2.4	2.6	0.0946	0.1024
L2	5.20	5.80	0.205	0.228
L3	2.20	3.20	0.087	0.126
F	0.03	0.23	0.0012	0.0091

10 Attentions

- Jiangsu Donghai Semiconductor Technology Co., Ltd. reserves the right to change the specification without prior notice! The customer should obtain the latest version of the information before making the order and verify that the information is complete and up to date.
- It is the responsibility of the purchaser for any failure or failure of any semiconductor product under certain conditions. It is the responsibility of the purchaser to comply with safety standards and to take safety measures in the system design and machine manufacturing of WXDH products in order to avoid potential risk of failure. Injury or property damage.
- Product promotion is endless, our company will be dedicated to provide customers with better products.

11 Appendix

Revision history:

Date	REV.	Description	Page
2017.03.19	1.0	Original	